



## TSH150

### WIDE BANDWIDTH AND BIPOLAR INPUTS SINGLE OPERATIONAL AMPLIFIER

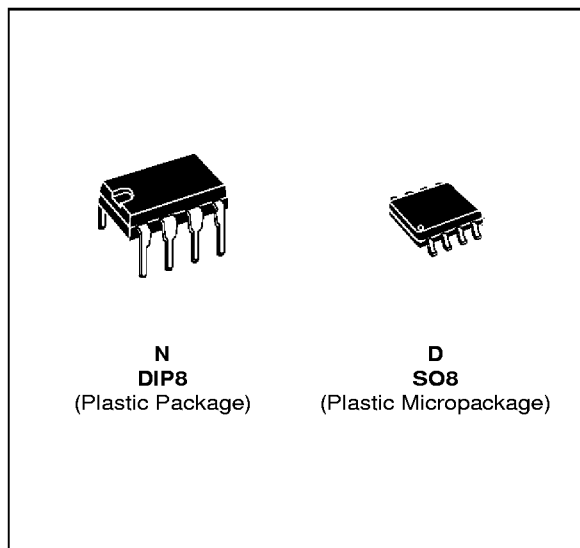
- LOW DISTORTION
- GAIN BANDWIDTH PRODUCT : 150MHz
- UNITY GAIN STABLE
- SLEW RATE : 190V/ $\mu$ s
- VERY FAST SETTTLING TIME : 20ns (0.1%)

#### DESCRIPTION:

The TSH150 is a wideband monolithic operational amplifier, internally compensated for unity-gain stability.

Low noise and low distortion, wide bandwidth and high linearity make this amplifier suitable for RF and video applications. Short circuit protection is provided by an internal current-limiting circuit.

The TSH150 has internal electrostatic discharge (ESD) protection circuits and fulfills MILSTD883C-Class2.

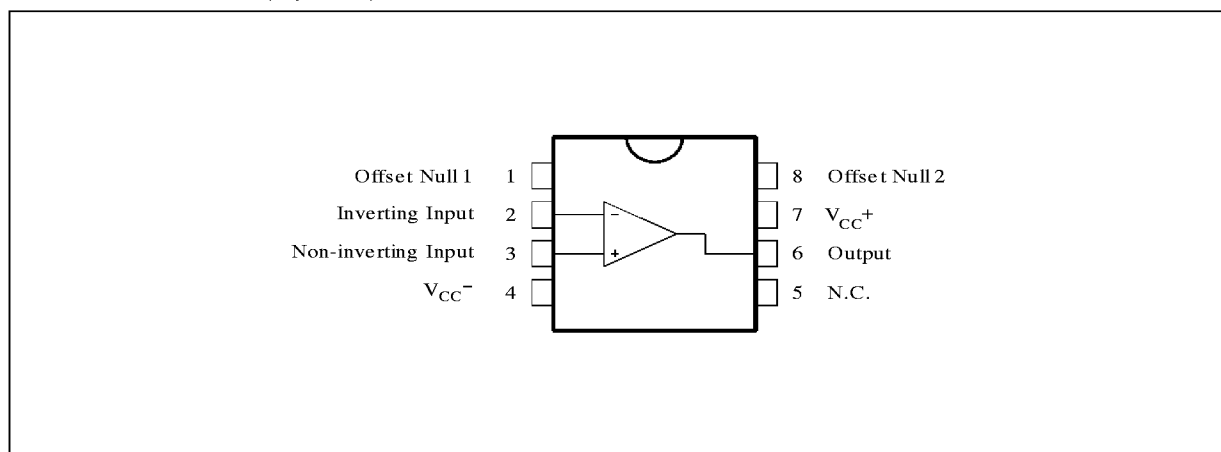


#### ORDER CODES

| Part Number | Temperature Range | Package |   |
|-------------|-------------------|---------|---|
|             |                   | N       | D |
| TSH150C     | 0°C, 70°C         | •       | • |
| TSH150I     | -40°C, 125°C      | •       | • |

150-01.TBL

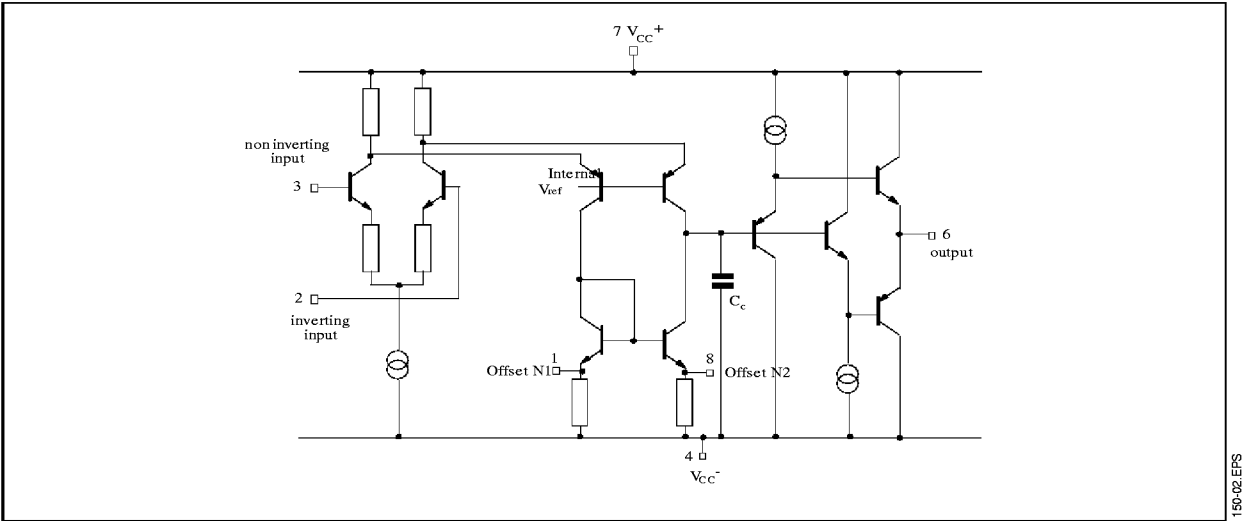
#### PIN CONNECTIONS (top view)



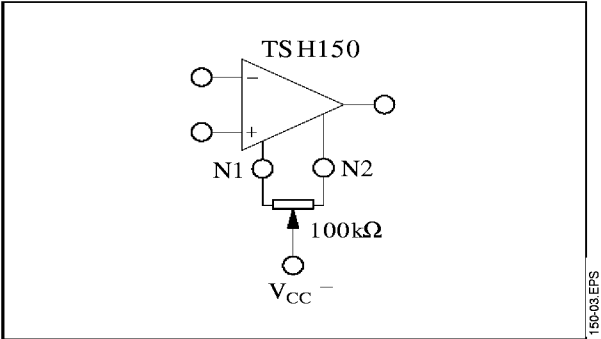
150-01.EPS

TSH150

SCHEMATIC DIAGRAM



INPUT OFFSET VOLTAGE NULL CIRCUIT



ABSOLUTE MAXIMUM RATINGS

| Symbol     | Parameter                                        |                    | Value                   | Unit               |
|------------|--------------------------------------------------|--------------------|-------------------------|--------------------|
| $V_{CC}$   | Supply Voltage                                   |                    | $\pm 7$                 | V                  |
| $V_{id}$   | Differential Input Voltage                       |                    | $\pm 5$                 | V                  |
| $V_i$      | Input Voltage Range                              |                    | $\pm 5$                 | V                  |
| $I_{in}$   | Current On Inputs<br>Current On Offset Null Pins |                    | $\pm 50$<br>$\pm 20$    | mA                 |
| $T_{oper}$ | Operating Free-Air Temperature Range             | TSH150C<br>TSH150I | 0 to +70<br>-40 to +125 | $^{\circ}\text{C}$ |
| $T_{stg}$  | Storage Temperature Range                        |                    | -65 to 150              | $^{\circ}\text{C}$ |

OPERATING CONDITIONS

| Symbol   | Parameter                       |  | Value                          | Unit |
|----------|---------------------------------|--|--------------------------------|------|
| $V_{CC}$ | Supply Voltage                  |  | $\pm 3$ to $\pm 6$             | V    |
| $V_{ic}$ | Common Mode Input Voltage Range |  | $V_{CC-} + 2$ to $V_{CC+} - 1$ | V    |



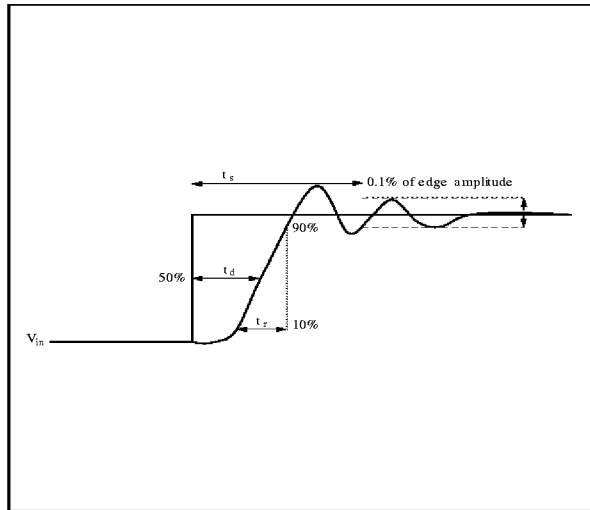
**ELECTRICAL CHARACTERISTICS** $V_{CC} = \pm 5V$ ,  $T_{amb} = 25^{\circ}C$  (unless otherwise specified)

| Symbol        | Parameter                                                                                                                                           | TSH150C, I                                     |                              |                      | Unit                   |
|---------------|-----------------------------------------------------------------------------------------------------------------------------------------------------|------------------------------------------------|------------------------------|----------------------|------------------------|
|               |                                                                                                                                                     | Min.                                           | Typ.                         | Max.                 |                        |
| $V_{io}$      | Input Offset Voltage<br>$T_{min} \leq T_{amb} \leq T_{max.}$                                                                                        |                                                | 0.3                          | 5<br>7               | mV                     |
| $DV_{io}$     | Input Offset Voltage Drift<br>$T_{min} \leq T_{amb} \leq T_{max.}$                                                                                  |                                                | 10                           |                      | $\mu V/^{\circ}C$      |
| $I_{ib}$      | Input Bias Current                                                                                                                                  |                                                | 5                            | 30                   | $\mu A$                |
| $I_{io}$      | Input Offset Current                                                                                                                                |                                                | 0.1                          | 2                    | $\mu A$                |
| $I_{CC}$      | Supply Current, no load<br>$T_{min} \leq T_{amb} \leq T_{max.}$<br>$V_{CC} = \pm 5V$<br>$V_{CC} = \pm 3V$<br>$V_{CC} = \pm 6V$<br>$V_{CC} = \pm 5V$ |                                                | 23<br>21<br>25               | 30<br>28<br>40<br>32 | mA                     |
| $A_{vd}$      | Large Signal Voltage Gain<br>$V_o = \pm 2.5V$<br>$R_L = \infty$<br>$R_L = 100\Omega$<br>$R_L = 50\Omega$                                            | 800<br>300<br>200                              | 1300<br>850<br>650           |                      | V/V                    |
| $V_{icm}$     | Input Common Mode Voltage Range                                                                                                                     | -3 to +4                                       | -3.5 to +4.5                 |                      | V                      |
| CMR           | Common Mode Rejection Ratio $V_{ic} = V_{icm \text{ min.}}$                                                                                         | 60                                             | 100                          |                      | dB                     |
| SVR           | Supply Voltage Rejection Ratio<br>$V_{CC} = \pm 5V$ to $\pm 3V$                                                                                     | 50                                             | 70                           |                      | dB                     |
| $V_o$         | Output Voltage<br>$R_L = 100\Omega$<br>$R_L = 50\Omega$<br>$T_{min} \leq T_{amb} \leq T_{max.}$<br>$R_L = 100\Omega$<br>$R_L = 50\Omega$            | $\pm 3$<br>$\pm 2.8$<br>$\pm 2.9$<br>$\pm 2.7$ | +3.5<br>-3.7<br>+3.3<br>-3.5 |                      | V                      |
| $I_o$         | Output Short Circuit Current<br>$V_{id} = \pm 1V$ , $V_o = 0V$                                                                                      | $\pm 50$                                       | $\pm 100$                    |                      | mA                     |
| GBP           | Gain Bandwidth Product<br>$A_{VCL} = 100$ , $R_L = 100\Omega$ , $C_L = 15pF$ , $f = 7.5MHz$                                                         |                                                | 150                          |                      | MHz                    |
| SR            | Slew Rate<br>$V_{in} = \pm 2V$ , $A_{VCL} = 1$ , $R_L = 100\Omega$ , $C_L = 15pF$                                                                   | 100                                            | 190                          |                      | V/ $\mu s$             |
| $e_n$         | Equivalent Input Voltage Noise<br>$R_S = 50\Omega$<br>$f_o = 1kHz$<br>$f_o = 10kHz$<br>$f_o = 100kHz$<br>$f_o = 1MHz$                               |                                                | 7<br>6.5<br>6.2<br>5.5       |                      | $\frac{nV}{\sqrt{Hz}}$ |
| $K_{ov}$      | Overshoot<br>$V_{in} = \pm 2V$ , $A_{VCL} = 1$ , $R_L = 100\Omega$ , $C_L = 15pF$                                                                   |                                                | 5                            |                      | %                      |
| $t_s$         | Settling Time 0.1% - (note 1)<br>$V_{in} = \pm 1V$ , $A_{VCL} = -1$                                                                                 |                                                | 20                           |                      | ns                     |
| $t_r$ , $t_f$ | Rise and Fall Time - (note 1)<br>$V_{in} = \pm 100mV$ , $A_{VCL} = 2$                                                                               |                                                | 3.5                          |                      | ns                     |
| $t_d$         | Delay Time - (note 1)<br>$V_{in} = \pm 100mV$ , $A_{VCL} = 2$                                                                                       |                                                | 2.5                          |                      | ns                     |
| $\phi_m$      | Phase Margin<br>$A_{VM} = 1$ , $R_L = 100\Omega$ , $C_L = 15pF$                                                                                     |                                                | 50                           |                      | Degrees                |
| THD           | Total Harmonic Distortion<br>$A_{VCL} = 10$ , $f = 1KHz$ , $V_o = \pm 2.5V$ , no load                                                               |                                                | 0.02                         |                      | %                      |
| FPB           | Full Power Bandwidth - (note 2)<br>$V_o = 5V_{pp}$ , $R_L = 100\Omega$<br>$V_o = 2V_{pp}$ , $R_L = 100\Omega$                                       |                                                | 12<br>30                     |                      | MHz                    |

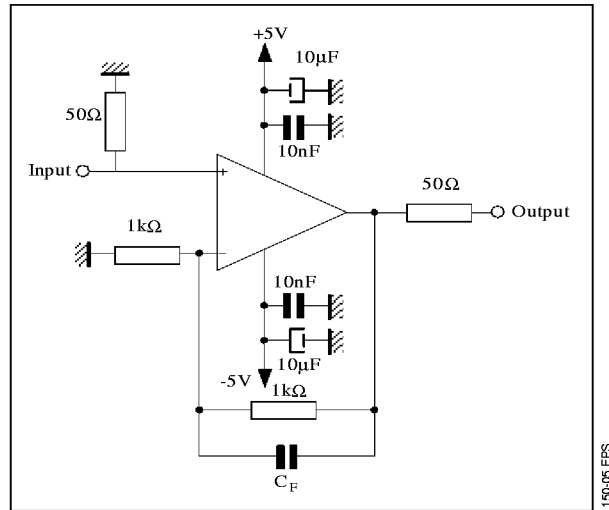
Note 1 : See test waveform figure

Note 2 : Full power bandwidth =  $\frac{SR}{\pi V_{opp}}$

## TEST WAVEFORM



## EVALUATION CIRCUIT



## PRINTED CIRCUIT LAYOUT

As for any high frequency device, a few rules must be observed when designing the PCB to get the best performances from this high speed op amp.

From the most to the least important points :

- Each power supply lead has to be bypassed to ground with a 10nF ceramic capacitor very close to the device and a 10μF tantalum capacitor.
- To provide low inductance and low resistance common return, use a ground plane or common point return for power and signal.
- All leads must be wide and as short as possible especially for op amp inputs. This is in order to decrease parasitic capacitance and inductance.
- Use small resistor values to decrease time constant with parasitic capacitance. Be aware on TSH150 device of the  $I_{IO}$  error and input noise currents with high feedback resistor values.
- Choose component sizes as small as possible (SMD).
- On output, decrease capacitor load so as to avoid circuit stability being degraded which may cause oscillation. You can also add a serial resistor in order to minimise its influence.
- One can add in parallel with feedback resistor a few pF ceramic capacitor  $C_F$  adjusted to optimize the settling time.

**MACROMODEL**

- LOW DISTORTION
- GAIN BANDWIDTH PRODUCT : 150MHz
- UNITY GAIN STABLE
- SLEW RATE : 190V/μs
- VERY FAST SETTTLING TIME : 20ns (0.1%)

**Applies to : TSH150C,I**

\*\* Standard Linear lcs Macromodels, 1993.

\*\* CONNECTIONS :

\* 1 INVERTING INPUT

\* 2 NON-INVERTING INPUT

\* 3 OUTPUT

\* 4 POSITIVE POWER SUPPLY

\* 5 NEGATIVE POWER SUPPLY

.SUBCKT TSH150 1 3 2 4 5 (analog)

\*\*\*\*\*

.MODEL MDTH D IS=1E-8 KF=1.568191E-15 CJO=10F

\* INPUT STAGE

CIP 2 5 1.000000E-12

CIN 1 5 1.000000E-12

EIP 10 5 2 5 1

EIN 16 5 1 5 1

RIP 10 11 1.040000E+02

RIN 15 16 1.040000E+02

RIS 11 15 3.264539E+02

DIP 11 12 MDTH 400E-12

DIN 15 14 MDTH 400E-12

VOFP 12 13 DC -9.162265E-05

VOFN 13 14 DC 0

IPOL 13 5 1.000000E-03

CPS 11 15 5.757255E-12

DINN 17 13 MDTH 400E-12

VIN 17 5 1.5000000E+00

DINR 15 18 MDTH 400E-12

VIP 4 18 0.500000E+00

FCP 4 5 VOFP 2.200000E+01

FCN 5 4 VOFN 2.200000E+01

FIBP 2 5 VOFP 1.000000E-02

FIBN 5 1 VOFN 1.000000E-02

\* AMPLIFYING STAGE

FIP 5 19 VOFP 4.370000E+02

FIN 5 19 VOFN 4.370000E+02

RG1 19 5 1.124121E+03

RG2 19 4 1.124121E+03

CC 19 29 2.000000E-09

HZTP 30 29 VOFP 5.574976E+01

HZTN 5 30 VOFN 5.574976E+01

DOPM 19 22 MDTH 400E-12

DONM 21 19 MDTH 400E-12

HOPM 22 28 VOUT 5.000000E+02

VIPM 28 4 5.000000E+01

HONM 21 27 VOUT 5.000000E+02

VINM 5 27 5.000000E+01

EOUT 26 23 19 5 1

VOUT 23 5 0

ROUT 26 3 2.180423E+01

COUT 3 5 1.000000E-12

DOP 19 25 MDTH 400E-12

VOP 4 25 1.511965E+00

DON 24 19 MDTH 400E-12

VON 24 5 1.511965E+00

.ENDS

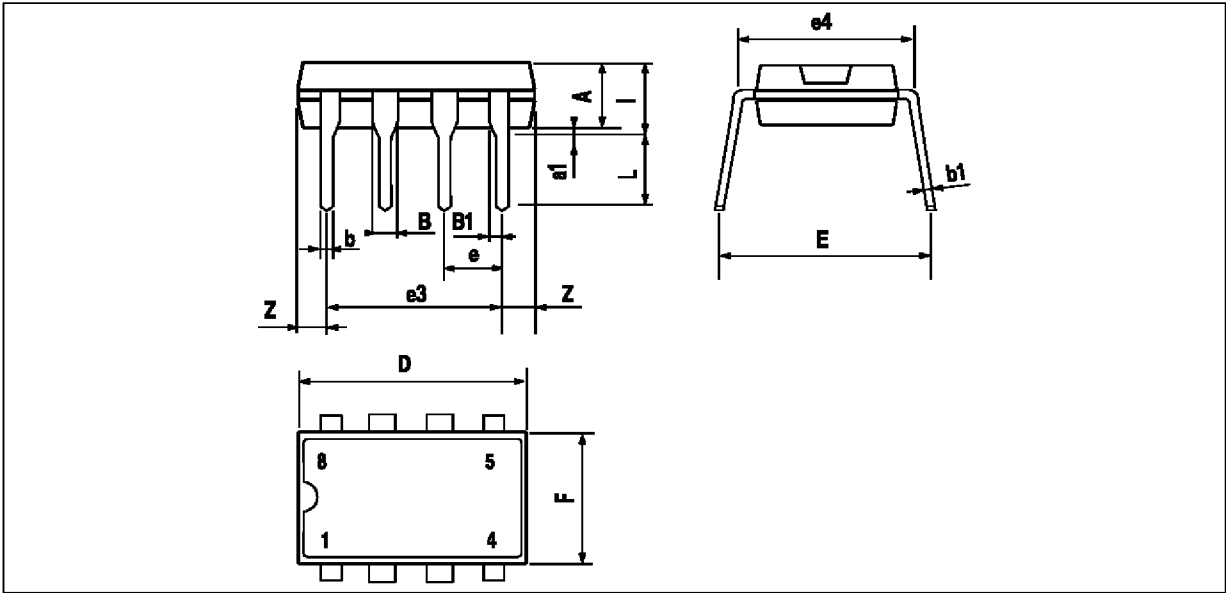
**ELECTRICAL CHARACTERISTICS**

$V_{CC} = \pm 5V$ ,  $T_{amb} = 25^{\circ}C$  (unless otherwise specified)

| Symbol          | Conditions                       | Value       | Unit    |
|-----------------|----------------------------------|-------------|---------|
| $V_{io}$        |                                  | 0           | mV      |
| $A_{vd}$        | $R_L = 100\Omega$                | 1           | V/mV    |
| $I_{CC}$        | No load                          | 21          | mA      |
| $V_{icm}$       |                                  | -3.5 to 4.5 | V       |
| $V_{OH}$        | $R_L = 100\Omega$                | +3.6        | V       |
| $V_{OL}$        | $R_L = 100\Omega$                | -3.6        | V       |
| $I_{sink}$      | $V_O = 0V$                       | 108         | mA      |
| $I_{source}$    | $V_O = 0V$                       | 108         | mA      |
| GBP             | $R_L = 100\Omega$ , $C_L = 15pF$ | 147         | MHz     |
| SR              | $R_L = 100\Omega$ , $C_L = 15pF$ | 180         | V/μs    |
| $\varnothing m$ | $R_L = 100\Omega$ , $C_L = 15pF$ | 42          | Degrees |
| $t_s$           | $A_v = -1$ at 0.1%               | 22.6        | ns      |

TSH150

PACKAGE MECHANICAL DATA  
8 PINS - PLASTIC DIP



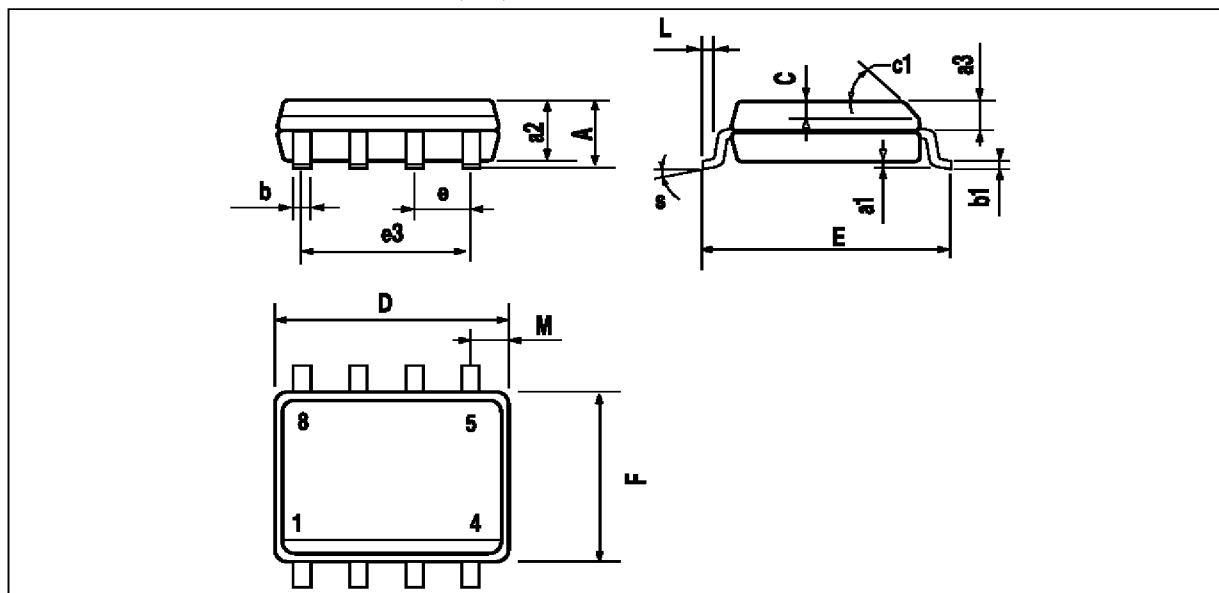
PM-DIP8.EPS

| Dimensions | Millimeters |      |       | Inches |       |       |
|------------|-------------|------|-------|--------|-------|-------|
|            | Min.        | Typ. | Max.  | Min.   | Typ.  | Max.  |
| A          |             | 3.32 |       |        | 0.131 |       |
| a1         | 0.51        |      |       | 0.020  |       |       |
| B          | 1.15        |      | 1.65  | 0.045  |       | 0.065 |
| b          | 0.356       |      | 0.55  | 0.014  |       | 0.022 |
| b1         | 0.204       |      | 0.304 | 0.008  |       | 0.012 |
| D          |             |      | 10.92 |        |       | 0.430 |
| E          | 7.95        |      | 9.75  | 0.313  |       | 0.384 |
| e          |             | 2.54 |       |        | 0.100 |       |
| e3         |             | 7.62 |       |        | 0.300 |       |
| e4         |             | 7.62 |       |        | 0.300 |       |
| F          |             |      | 6.6   |        |       | 0.260 |
| i          |             |      | 5.08  |        |       | 0.200 |
| L          | 3.18        |      | 3.81  | 0.125  |       | 0.150 |
| Z          |             |      | 1.52  |        |       | 0.060 |

DIP8.TBL



# **PACKAGE MECHANICAL DATA** **8 PINS - PLASTIC MICROPACKAGE (SO)**



PM-SO8.EPS

| Dimensions | Millimeters |      |      | Inches |       |       |
|------------|-------------|------|------|--------|-------|-------|
|            | Min.        | Typ. | Max. | Min.   | Typ.  | Max.  |
| A          |             |      | 1.75 |        |       | 0.069 |
| a1         | 0.1         |      | 0.25 | 0.004  |       | 0.010 |
| a2         |             |      | 1.65 |        |       | 0.065 |
| a3         | 0.65        |      | 0.85 | 0.026  |       | 0.033 |
| b          | 0.35        |      | 0.48 | 0.014  |       | 0.019 |
| b1         | 0.19        |      | 0.25 | 0.007  |       | 0.010 |
| C          | 0.25        |      | 0.5  | 0.010  |       | 0.020 |
| c1         | 45° (typ.)  |      |      |        |       |       |
| D          | 4.8         |      | 5.0  | 0.189  |       | 0.197 |
| E          | 5.8         |      | 6.2  | 0.228  |       | 0.244 |
| e          |             | 1.27 |      |        | 0.050 |       |
| e3         |             | 3.81 |      |        | 0.150 |       |
| F          | 3.8         |      | 4.0  | 0.150  |       | 0.157 |
| L          | 0.4         |      | 1.27 | 0.016  |       | 0.050 |
| M          |             |      | 0.6  |        |       | 0.024 |
| S          | 8° (max.)   |      |      |        |       |       |

SO8.TBL

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